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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



DATA SHEET



NPN SILICON RF TRANSISTOR

NE68130 / 2SC4227 JEITA Part No.

NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW-NOISE AMPLIFICATION 3-PIN SUPER MINIMOLD

DESCRIPTION

The NE68130 / 2SC4227 is a low supply voltage transistor designed for VHF, UHF low noise amplifier. It is suitable for a high density surface mount assembly since the transistor has been applied 3-pin super minimold package.

FEATURES

- Low noise : $NF = 1.4 \text{ dB TYP. @ } V_{CE} = 3 \text{ V, } I_c = 7 \text{ mA, } f = 1 \text{ GHz}$
- High gain : $|S_{21e}|^2 = 12 \text{ dB TYP. @ } V_{CE} = 3 \text{ V, } I_c = 7 \text{ mA, } f = 1 \text{ GHz}$
- 3-pin super minimold package

★ ORDERING INFORMATION

Part Number	Quantity	Supplying Form
NE68130 -A 2SC4227 -A	50 pcs (Non reel)	<ul style="list-style-type: none"> • 8 mm wide embossed taping • Pin 3 (Collector) face the perforation side of the tape
NE68130-T1-A 2SC4227-T1-A	3 kpcs/reel	

Remark To order evaluation samples, contact your nearby sales office.
The unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS ($T_A = +25^\circ\text{C}$)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V_{CBO}	20	V
Collector to Emitter Voltage	V_{CEO}	10	V
Emitter to Base Voltage	V_{EBO}	1.5	V
Collector Current	I_c	65	mA
Total Power Dissipation	P_{tot}^{Note}	150	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to +150	$^\circ\text{C}$

Note Free air

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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ELECTRICAL CHARACTERISTICS (T_A = +25°C)

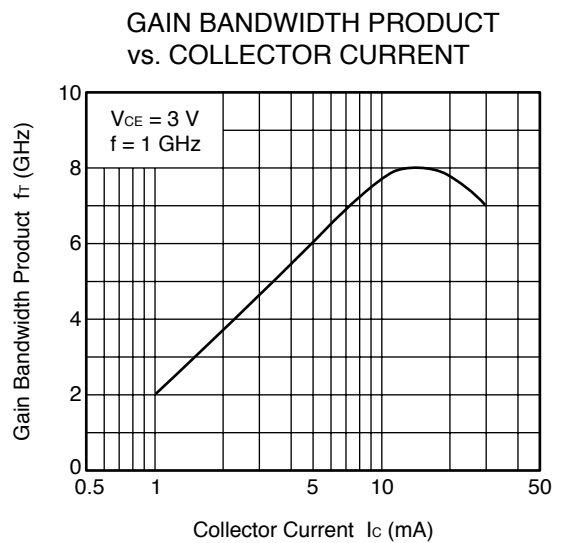
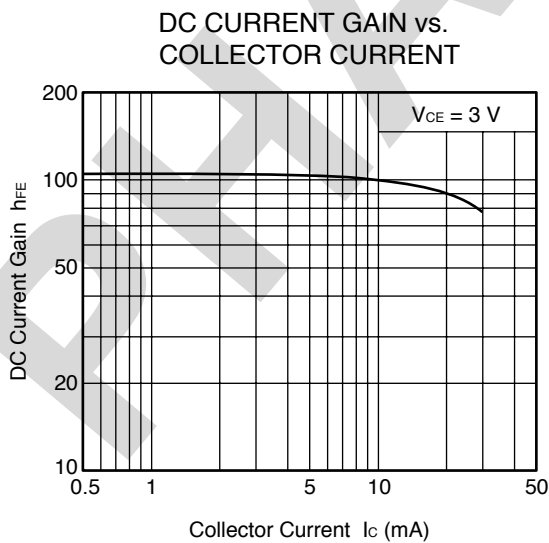
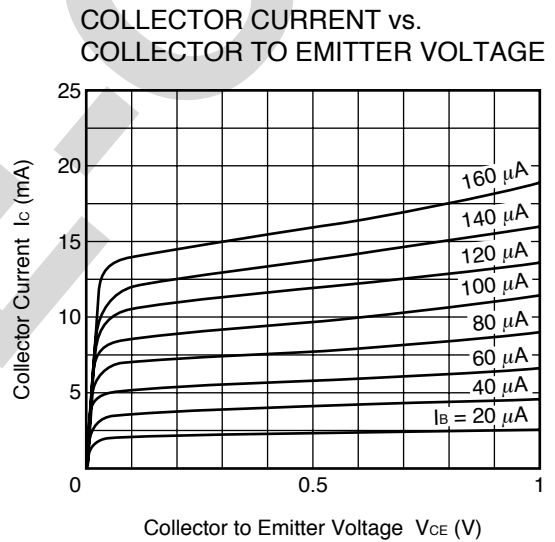
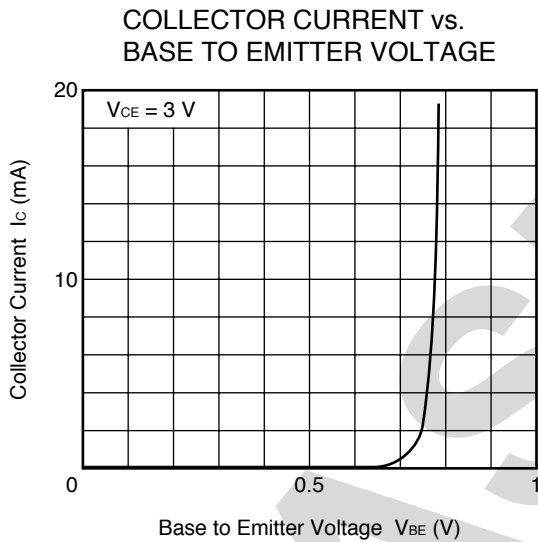
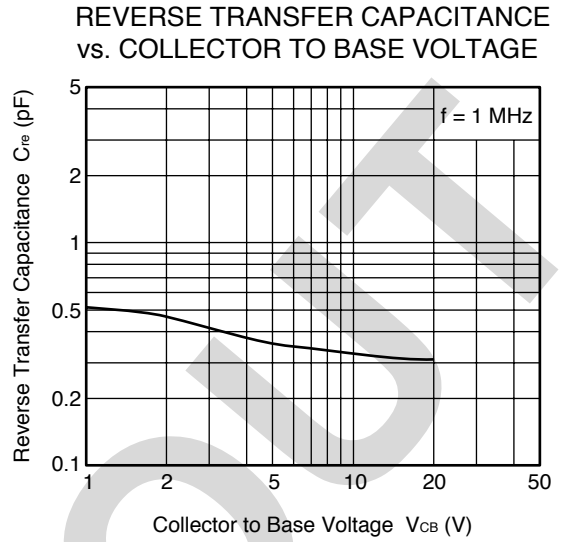
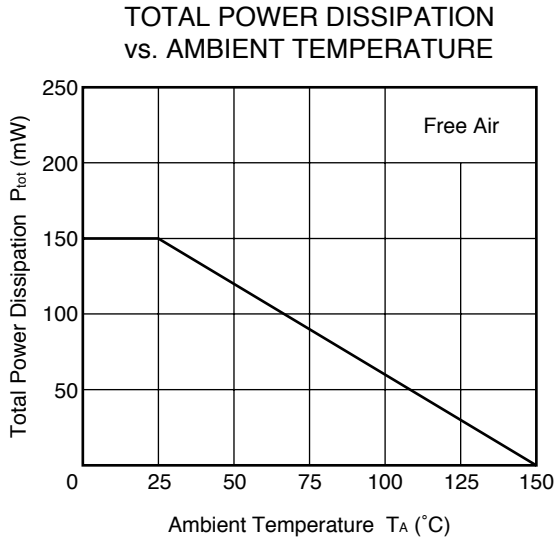
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	I _{CBO}	V _{CB} = 10 V, I _E = 0 mA	-	-	0.8	μA
Emitter Cut-off Current	I _{EBO}	V _{EB} = 1 V, I _C = 0 mA	-	-	0.8	μA
DC Current Gain	h _{FE} ^{Note 1}	V _{CE} = 3 V, I _C = 7 mA	40	-	240	-
RF Characteristics						
Gain Bandwidth Product	f _T	V _{CE} = 3 V, I _C = 7 mA	4.5	7.0	-	GHz
Insertion Power Gain	S _{21e} ²	V _{CE} = 3 V, I _C = 7 mA, f = 1 GHz	10	12	-	dB
Noise Figure	NF	V _{CE} = 3 V, I _C = 7 mA, f = 1 GHz	-	1.4	2.7	dB
★ Reverse Transfer Capacitance	C _{re} ^{Note 2}	V _{CB} = 3 V, I _E = 0 mA, f = 1 MHz	-	0.45	0.9	pF

- Notes**
1. Pulse measurement: PW ≤ 350 μs, Duty Cycle ≤ 2%
 2. Collector to base capacitance when the emitter grounded

h_{FE} CLASSIFICATION

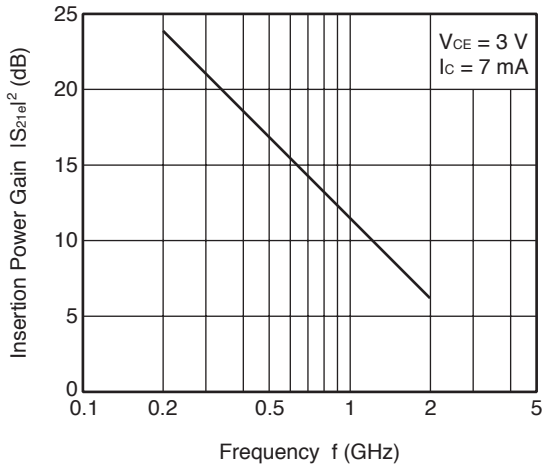
Rank	R33	R34	R35
Marking	R33	R34	R35
h _{FE} Value	40 to 90	70 to 150	110 to 240

TYPICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, unless otherwise specified)

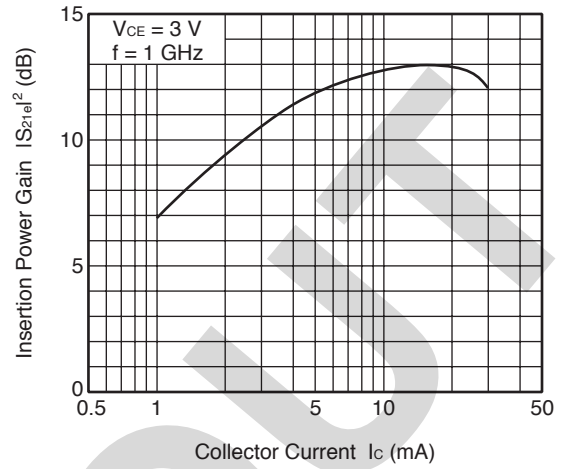


Remark The graphs indicate nominal characteristics.

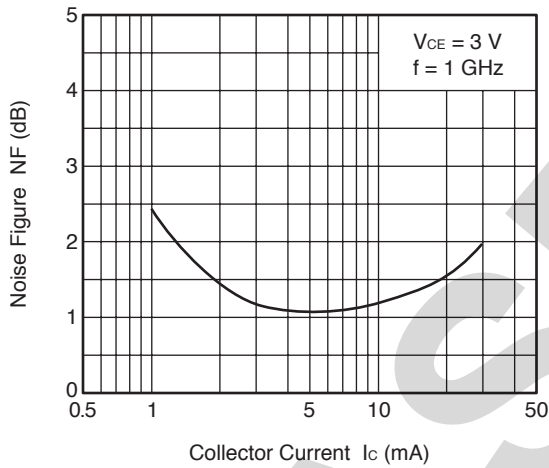
INSERTION POWER GAIN vs. FREQUENCY



INSERTION POWER GAIN vs. COLLECTOR CURRENT



NOISE FIGURE vs. COLLECTOR CURRENT



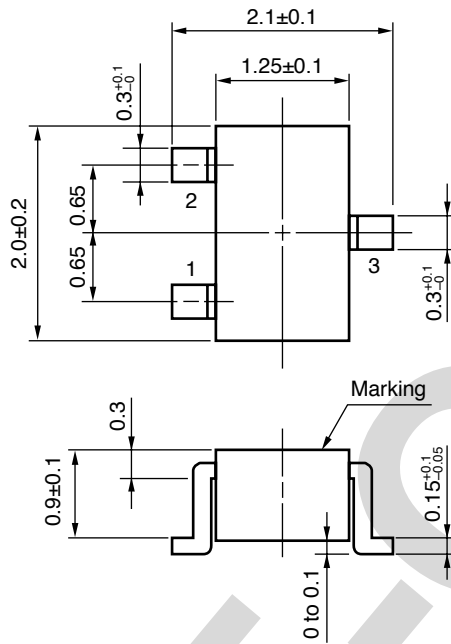
Remark The graphs indicate nominal characteristics.

S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- URL <http://www.necel.com/microwave/en/>

PACKAGE DIMENSIONS

3-PIN SUPER MINIMOLD (UNIT: mm)



PIN CONNECTIONS

- 1. Emitter
 - 2. Base
 - 3. Collector
- (EIAJ : SC-70)

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